NSN 5962-01-351-5726

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-351-5726

View Offiline at https://derobasegroup.com/his//0902-01-001-0720
Body Length:
Between 0.342 inches and 0.358 inches
Body Width:
Between 0.342 inches and 0.358 inches
Body Height:
Between 0.060 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.1 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and bipolar and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
C-2 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, programmed pal, and/or invert gate array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 12.0 volts power source
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 leadless
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:

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